

HIGH POWER PIN DIODES

RoHS Compliant Versions Available

DESCRIPTION

The UM4000 and UM4900 series features high power PIN diodes with long carrier lifetimes and thick I-regions. They are especially suitable for use in low distortion switches and attenuators, in HF through S band frequencies. While both series are electrically equivalent, the UM4900 series have higher power ratings due to a shorter thermal path between the chip and package. High charge storage and long carrier lifetime enable high RF levels to be controlled with relatively low bias current.

Similarly, peak RF voltages can be handled well in excess of applied reverse bias voltage.

Both series have been fully qualified in high power UHF phase shifters and megawatt peak-power duplexers, accumulating thousands of hours of proven performance. Both types have been used in the design of antenna selectors and couplers, where inductance and capacitance elements are switched in and out of filter or cavity networks.

The standard finish for the UM4000 series is Sn/Pb. For RoHS compliant devices, use the UMX prefix. (IE: UMX4000SM) The UMX series meets RoHS requirements per EU Directive 2002/95/EC.

IMPORTANT: For themost current data, consult *MICROSEMI*'s website: www.microsemi.com

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED) Condition **UM4000 UM4900 Package** θ (°C/W) θ (°C/W) PD (W) PD (W) 25 °C Pin Temperature Α 25 6 37.5 4 ½ in. total length to 25 °C Contact 12 1.25 12 12.5 **B & E** Free Air 2.5 2.5 25 °C Stud Temperature С 25 37.5 6 4 25 °C Stud Temperature 18.75 6 D 8 25 SM 25 °C End Cap Temperature 20 7 N/A ΑII 1 us pulse (Single) 100 kW 100 kW

VOLTAGE RATINGS					
Reverse Voltage @ 10 uA	UM4000	UM4900			
100	UM4001	UM4901			
200	UM4002	UM4902			
400	-	-			
600	UM4006	UM4906			
1000	UM4010	-			

KEY FEATURES

- Voltage ratings to 1000 V
- Power dissipation to 37.5 W
- Series resistance rated at 0.5 Ω
- Carrier lifetime greater than 5 µs
- Non cavity design
- RoHS compliant version available ¹
- Thermally matched configuration
- Low capacitance at 0 V bias
- Low conductance at 0 V bias
- Compatible with automatic insertion equipment
- 1- RoHS compliant version is supplied with a matte tin finish. (Order UMX4000, UMX4900)





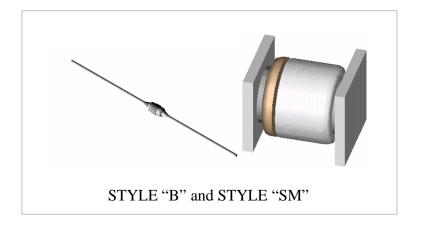
- Isolated stud package available
- Surface mount package available



HIGH POWER PIN DIODES

RoHS Compliant Versions Available

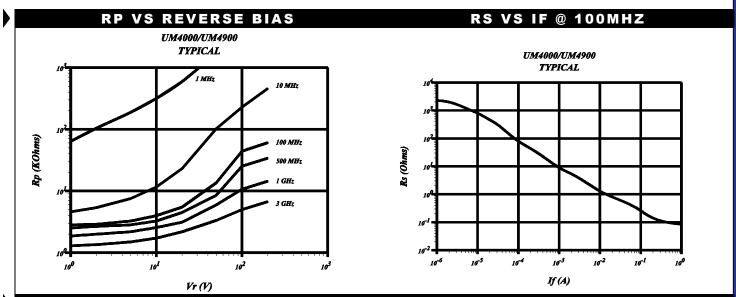
ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)						
Parameter	Symbol	Conditions	Min	Тур.	Max	Units
Forward Voltage	VF	I _F = 100 mA			1.0	V
Reverse Current	I _R	At rated voltage			10	uA
Series Resistance	Rs	If = 100 mA, F= 100 MHz		0.3	0.5	Ohm
Capacitance	Ст	V _R = 100 V, F = 1 MH _Z		2.4	3	pF
Parallel Resistance	R _P	V _R = 100 V, F = 100 MHz	10k	15k		Ohms
Carrier Lifetime	τ	I _F = 10 mA	5	10		uS





HIGH POWER PIN DIODES

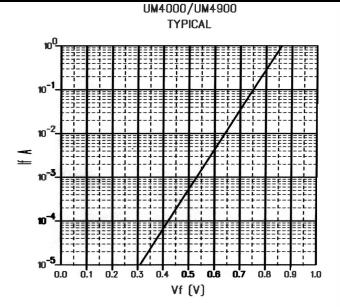
RoHS Compliant Versions Available



CT VS REVERSE VOLTAGE

UM4000/UM4900 TYPICAL CAPACITANCE (pF) Vr (VOLTS)

VF VS IF



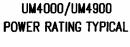


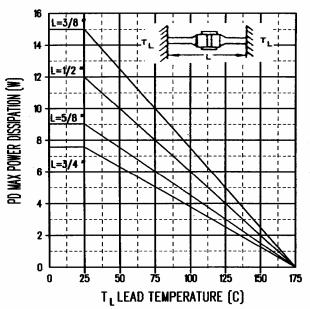
HIGH POWER PIN DIODES

RoHS Compliant Versions Available

TYPICAL POWER RATINGS

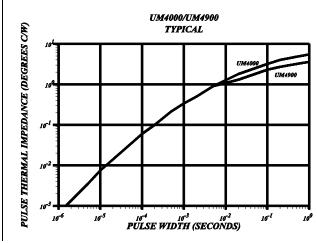
TYPICAL POWER RATINGS





PULSED THERMAL IMPEDANCE

STUD TEMPERATURE (C)

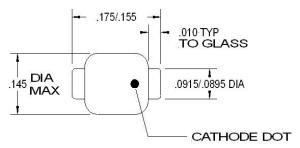




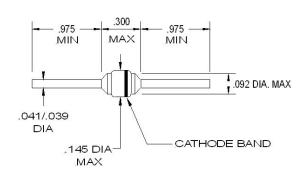
HIGH POWER PIN DIODES

RoHS Compliant Versions Available

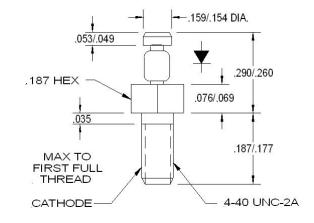




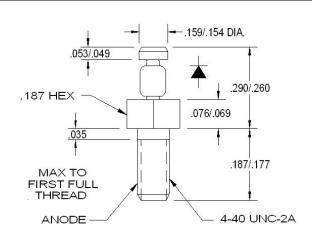
STYLE "B"



STYLE "C"



STYLE "CR"

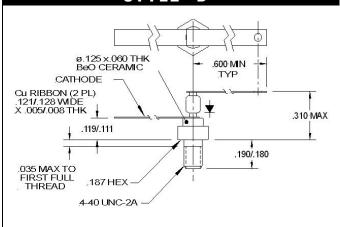




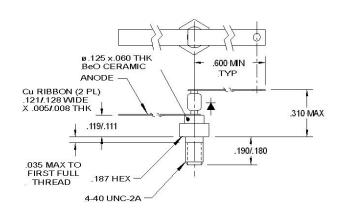
HIGH POWER PIN DIODES

RoHS Compliant Versions Available

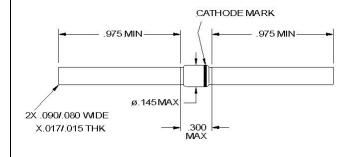




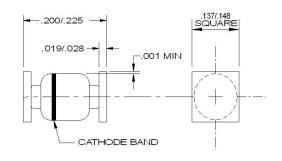
STYLE "DR"



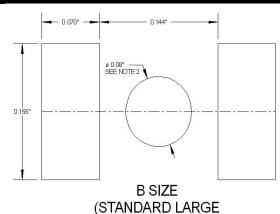
STYLE "E"



STYLE "SM"



STYLE "SM" FOOTPRINT



SQUARE END CAP OUTLINE)

STYLE "SM" FOOTPRINT NOTES

Notes:

- Footprint dimensions the terminals and allow for a solder fillet on each end provided placement accuracy is within 0.005"
- If the mounting method chosen requires the use of an adhesive in addition to the solder, then a round or square spot of adhesive should be centrally located as shown.



HIGH POWER PIN DIODES

RoHS Compliant Versions Available

•	NOTES:
•	

NOTE